NSN 5962-01-024-4404

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View Online at https://aerobasegroup.com/nsn/5962-01-024-4404

View Offiline at https://derobasegroup.com/his//5502-01-024-4404
Body Length:
Between 1.100 inches and 1.250 inches
Body Width:
Between 0.580 inches and 0.610 inches
Body Height:
Between 0.080 inches and 0.120 inches
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Misc sras
Features Provided:
Hermetically sealed and programmed and w/disable and w/enable
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
8 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
5.5 volts power source
Time Rating Per Chacteristic:
45.00 nanoseconds propagation delay time, low to high level output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Test Data Document:
30003-247as-c2263 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing
etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a
Unit Of Measure:

Yes - demil/mli

Demilitarization:

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